

Phase Control Thyristors (Hockey PUK Version), 410 A



A-PUK (TO-200AB)

| PRIMARY CHARACTERISTICS | | | | | |
|------------------------------------|---|--|--|--|--|
| I _{T(AV)} | 410 A | | | | |
| V _{DRM} /V _{RRM} | 400 V, 800 V, 1200 V, 1400 V, 1600 V, 1800 V, 2000 V | | | | |
| V _{TM} | 1.69 V | | | | |
| I _{GT} | 90 mA | | | | |
| T _J | -40 °C to +125 °C | | | | |
| Package | A-PUK (TO-200AB) | | | | |
| Circuit configuration | Single SCR | | | | |

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-PUK (TO-200AB)



- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|------------------------------------|-----------------|-------------|-------------------|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | |
| 1 | | 410 | A | | | |
| I _{T(AV)} | T _{hs} | 55 | °C | | | |
| 1 | | 780 | A | | | |
| I _T (RMS) | T _{hs} | 25 | °C | | | |
| | 50 Hz | 5700 | A | | | |
| ITSM | 60 Hz | 5970 | | | | |
| l ² t | 50 Hz | 163 | kA ² s | | | |
| I-T | 60 Hz | 149 | KA-S | | | |
| V _{DRM} /V _{RRM} | | 400 to 2000 | V | | | |
| t _q | Typical | 100 | μs | | | |
| T _J | | -40 to +125 | °C | | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | | | |
|-----------------|-----------------|---|--|---|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V | I_{DRM}/I_{RRM} , MAXIMUM AT $T_J = T_J$ MAXIMUM mA | | | | |
| | 04 | 400 | 500 | | | | | |
| | 08 | 800 | 900 | | | | | |
| | 12 | 1200 | 1300 | | | | | |
| VS-ST230CC | 14 | 1400 | 1500 | 30 | | | | |
| | 16 | 1600 | 1700 | | | | | |
| | 18 | 1800 | 1900 | | | | | |
| | 20 | 2000 | 2100 | | | | | |

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| ABSOLUTE MAXIMUM RATINGS | S | | | | | |
|---|---------------------|---|--|-----------------------------|------------|---------------------|
| PARAMETER | SYMBOL | | VALUES | UNITS | | |
| Maximum average on-state current | _ | 180° condu | 180° conduction, half sine wave | | | Α |
| at heatsink temperature | $I_{T(AV)}$ | double side | (single side) co | oled | 55 (85) | °C |
| Maximum RMS on-state current | I _{T(RMS)} | DC at 25 °C | heatsink tempe | erature double side cooled | 780 | |
| | | t = 10 ms | No voltage | | 5700 | |
| Maximum peak, one-cycle | ı | t = 8.3 ms | reapplied | | 5970 | A kA ² s |
| non-repetitive surge current | ITSM | t = 10 ms 100 % V _s | 100 % V _{RRM} | | 4800 | |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave. | 5000 | |
| Maximum I ² t for fusing | | t = 10 ms | No voltage reapplied | initial $T_J = T_J$ maximum | 163 | |
| | l ² t | t = 8.3 ms | | | 148 | |
| | | t = 10 ms | | | 115 | |
| | | t = 8.3 ms | reapplied | | 105 | |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 to 10 | t = 0.1 to 10 ms, no voltage reapplied | | | kA²√s |
| Low level value of threshold voltage | V _{T(TO)1} | (16.7 % x π | (16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum | | | V |
| High level value of threshold voltage | V _{T(TO)2} | $(I > \pi \times I_{T(AV)})$ | $(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ | | |] |
| Low level value of on-state slope resistance | r _{t1} | (16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum | | | 0.88 | |
| High level value of on-state slope resistance | r _{t2} | $(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ | | | 0.81 | mΩ |
| Maximum on-state voltage | V_{TM} | $I_{pk} = 880 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$ | | | 1.69 | V |
| Maximum holding current | I _H | T _ 05 °C | anada aunabi 1 | 2 V registive lead | 600 | m A |
| Maximum (typical) latching current | IL | T _J = 25 °C, anode supply 12 V resistive load | | | 1000 (300) | mA |

| SWITCHING | | | | | | |
|--|----------------|---|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum non-repetitive rate of rise of turned-on current | dl/dt | Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$ | 1000 | A/µs | | |
| Typical delay time | t _d | Gate current 1 A, $dl_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$ | 1.0 | | | |
| Typical turn-off time | t _q | I_{TM} = 300 A, T_J = T_J maximum, dl/dt = 20 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs | 100 | μs | | |

| BLOCKING | | | | | | |
|--|--|--|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum critical rate of rise of off-state voltage | dV/dt | $T_J = T_J$ maximum linear to 80 % rated V_{DRM} | 500 | V/µs | | |
| Maximum peak reverse and off-state leakage current | I _{RRM} , I _{DRM} | $T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied | 30 | mA | | |



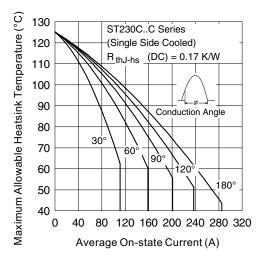
| TRIGGERING | | | | | | |
|-------------------------------------|--------------------|--------------------------|--|------|------|-------|
| PARAMETER | SYMBOL | TE | TEST CONDITIONS | | | UNITS |
| PANAIWETEN | STINIBOL | 16 | ST CONDITIONS | TYP. | MAX. | UNITS |
| Maximum peak gate power | P _{GM} | $T_J = T_J$ maximum, | $t_p \le 5 \text{ ms}$ | 10 | 0.0 | W |
| Maximum average gate power | P _{G(AV)} | $T_J = T_J$ maximum, | f = 50 Hz, d% = 50 | 2 | .0 | VV |
| Maximum peak positive gate current | I _{GM} | $T_J = T_J$ maximum, | $t_p \le 5 \text{ ms}$ | 3 | .0 | Α |
| Maximum peak positive gate voltage | + V _{GM} | T. – T. mavimum | t < 5 mg | 2 | 0 | V |
| Maximum peak negative gate voltage | - V _{GM} | TJ = TJ IIIaxiiIIuiii, | $T_J = T_J$ maximum, $t_p \le 5$ ms | | | v |
| | I _{GT} | T _J = - 40 °C | | 180 | - | |
| DC gate current required to trigger | | T _J = 25 °C | Maximum required gate trigger/ | 90 | 150 | mA |
| | | T _J = 125 °C | current/voltage are the lowest | 40 | - | |
| | | T _J = - 40 °C | value which will trigger all units | 2.9 | - | |
| DC gate voltage required to trigger | V _{GT} | T _J = 25 °C | 12 V anode to cathode applied | 1.8 | 3.0 | V |
| | | T _J = 125 °C | | 1.2 | - | |
| DC gate current not to trigger | I _{GD} | | Maximum gate current/voltage | 10 | | mA |
| DC gate voltage not to trigger | V _{GD} | $T_J = T_J maximum$ | not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied | 0.25 | | V |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|---------------------------------------|---------------------|---|---------------|-----------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum operating temperature range | TJ | | -40 to 125 | - °C | |
| Maximum storage temperature range | T _{Stg} | | -40 to 150 | | |
| Maximum thermal resistance, | В | DC operation single side cooled | 0.17 | | |
| junction to heatsink | R _{thJ-hs} | DC operation double side cooled | 0.08 | K/W | |
| Maximum thermal resistance, | Б | DC operation single side cooled | 0.033 | | |
| case to heatsink | | DC operation double side cooled | 0.017 | | |
| Mounting force, ± 10 % | | | 4900 (500) | N (kg) | |
| Approximate weight | | | 50 | g | |
| Case style | | See dimensions - link at the end of datasheet | A-PUK (TO-2 | 00AB) | |

| △R _{thJC} CONDUCTION | | | | | | | |
|-------------------------------|-----------------------|-------------|-------------|--------------|---------------------|--------|--|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | | RECTANGULAR | R CONDUCTION | TEST CONDITIONS | LIMITE | |
| CONDUCTION ANGLE | SINGLE SIDE | DOUBLE SIDE | SINGLE SIDE | DOUBLE SIDE | TEST CONDITIONS | UNITS | |
| 180° | 0.015 | 0.017 | 0.011 | 0.011 | $T_J = T_J$ maximum | | |
| 120° | 0.018 | 0.019 | 0.019 | 0.019 | | | |
| 90° | 0.024 | 0.024 | 0.026 | 0.026 | | K/W | |
| 60° | 0.035 | 0.035 | 0.036 | 0.036 | | | |
| 30° | 0.060 | 0.060 | 0.060 | 0.061 | | | |

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



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Fig. 1 - Current Ratings Characteristics

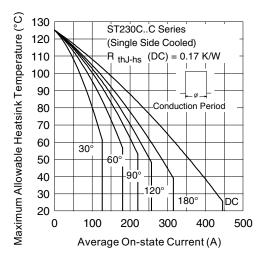


Fig. 2 - Current Ratings Characteristics

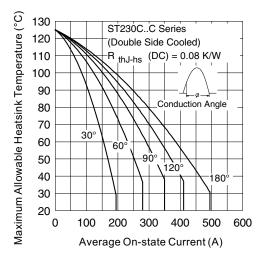


Fig. 3 - Current Ratings Characteristics

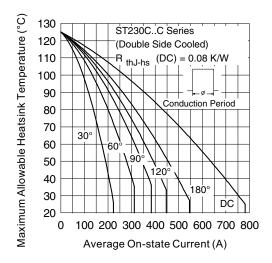


Fig. 4 - Current Ratings Characteristics

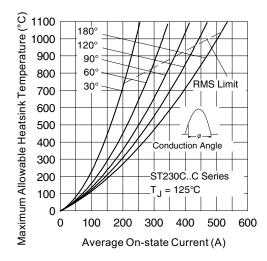


Fig. 5 - On-State Power Loss Characteristics

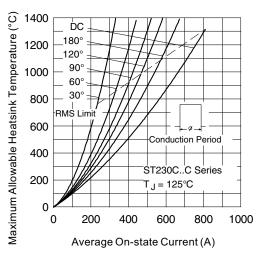


Fig. 6 - On-State Power Loss Characteristics

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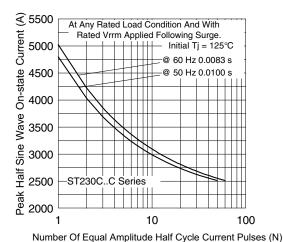


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

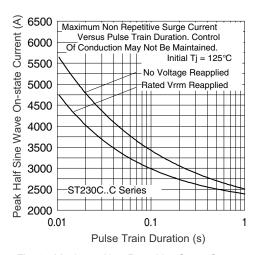


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

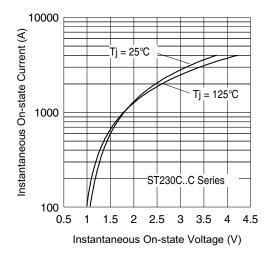


Fig. 9 - On-State Voltage Drop Characteristics

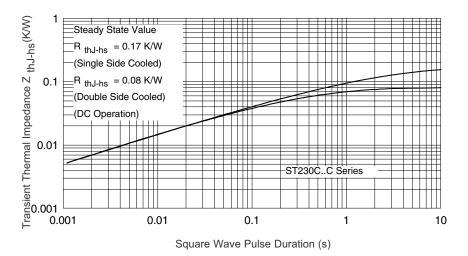


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

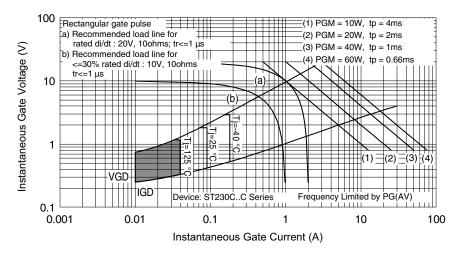
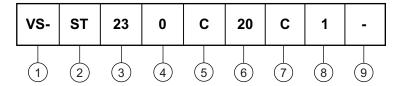


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Thyristor

Essential part number

4 - 0 = converter grade

5 - C = ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - C = PUK case A-PUK (TO-200AB)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

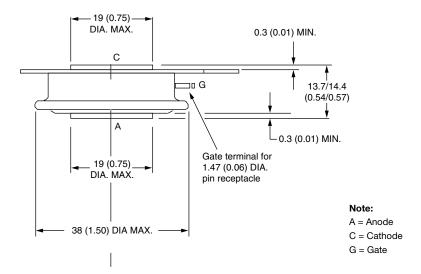
| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95074 | | | |

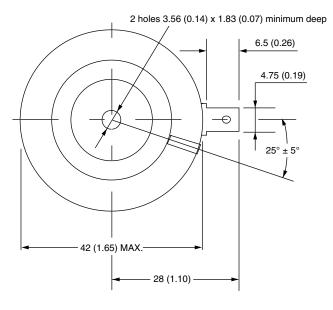


A-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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